



SMCG Plastic-Encapsulate Diodes

SMDJ SERIES Transient Voltage Suppressor Diodes

Features

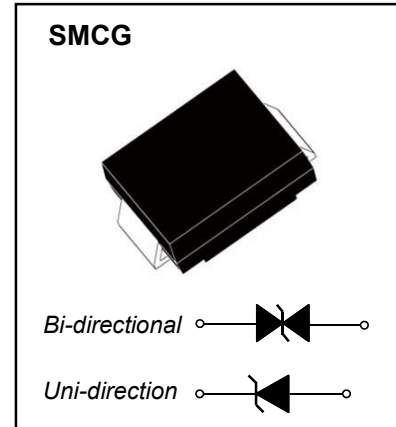
- P_{PP} 3000W
- V_{RWM} 5.0V- 440V
- Glass passivated chip
- AECQ 101 qualified

Applications

- Clamping Voltage

Marking

- SMDJ XXCA/XXA
XX : From 5.0 To 440



Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Conditions	Max
Peak pulse power dissipation	P _{PPM}	W	with a 10/1000us waveform	3000
Peak pulse current(1)	I _{PPM}	A	with a 10/1000us waveform	See Next Table
Peak forward surge current(2)	I _{FSM}	A	8.3ms single half sine-wave unidirectional only	300
Operating junction and storage temperature range	T _J , T _{STG}	°C		-55 to +150

Notes:

- (1) Non-repetitive current pulse, per Fig. 3 and derated above T_A = 25°C per Fig.2.
- (2) Mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pads to each terminal
- (3) VF < 3.5V for devices of VBR < 200V and VF < 5.0V for devices of VBR > 201V

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Part Number Add C For Bi-Directional (Note 4)	Reverse Standoff Voltage V_{RWM} (V)	Breakdown Voltage V_{BR} @ I_T (Note 5)		Test Current I_T (mA)	Max. Reverse Leakage @ V_{RWM} (Note 6) I_R (μA)	Max. Clamping Voltage @ I_{pp} V_C (V)	Max. Peak Pulse Current I_{pp} (A)
		Min (V)	Max (V)				
SMDJ5.0(C)A	5.0	6.40	7.00	10	800	9.2	326.09
SMDJ6.0(C)A	6.0	6.67	7.37	10	800	10.3	291.26
SMDJ6.5(C)A	6.5	7.22	7.98	10	500	11.2	267.86
SMDJ7.0(C)A	7.0	7.78	8.60	10	200	12.0	250.00
SMDJ7.5(C)A	7.5	8.33	9.21	1.0	100	12.9	232.56
SMDJ8.0(C)A	8.0	8.89	9.83	1.0	50	13.6	220.59
SMDJ8.5(C)A	8.5	9.44	10.40	1.0	20	14.4	208.33
SMDJ9.0(C)A	9.0	10.00	11.10	1.0	10	15.4	194.81
SMDJ10(C)A	10.0	11.10	12.30	1.0	5.0	17.0	176.47
SMDJ11(C)A	11.0	12.20	13.50	1.0	5.0	18.2	164.84
SMDJ12(C)A	12.0	13.30	14.70	1.0	2.0	19.9	150.75
SMDJ13(C)A	13.0	14.40	15.90	1.0	2.0	21.5	139.53
SMDJ14(C)A	14.0	15.60	17.20	1.0	2.0	23.2	129.31
SMDJ15(C)A	15.0	16.70	18.50	1.0	1.0	24.4	122.95
SMDJ16(C)A	16.0	17.80	19.70	1.0	1.0	26.0	115.38
SMDJ17(C)A	17.0	18.90	20.90	1.0	1.0	27.6	108.70
SMDJ18(C)A	18.0	20.00	22.10	1.0	1.0	29.2	102.74
SMDJ20(C)A	20.0	22.20	24.50	1.0	1.0	32.4	92.59
SMDJ22(C)A	22.0	24.40	26.90	1.0	1.0	35.5	84.51
SMDJ24(C)A	24.0	26.70	29.50	1.0	1.0	38.9	77.12
SMDJ26(C)A	26.0	28.90	31.90	1.0	1.0	42.1	71.26
SMDJ28(C)A	28.0	31.10	34.40	1.0	1.0	45.4	66.08
SMDJ30(C)A	30.0	33.30	36.80	1.0	1.0	48.4	61.98
SMDJ33(C)A	33.0	36.70	40.60	1.0	1.0	53.3	56.29
SMDJ36(C)A	36.0	40.00	44.20	1.0	1.0	58.1	51.64
SMDJ40(C)A	40.0	44.40	49.10	1.0	1.0	64.5	46.51
SMDJ43(C)A	43.0	47.80	52.80	1.0	1.0	69.4	43.23
SMDJ45(C)A	45.0	50.00	55.30	1.0	1.0	72.7	41.27
SMDJ48(C)A	48.0	53.30	58.90	1.0	1.0	77.4	38.76
SMDJ51(C)A	51.0	56.70	62.70	1.0	1.0	82.4	36.41
SMDJ54(C)A	54.0	60.00	66.30	1.0	1.0	87.1	34.44
SMDJ58(C)A	58.0	64.40	71.20	1.0	1.0	93.6	32.05
SMDJ60(C)A	60.0	66.70	73.70	1.0	1.0	96.8	30.99
SMDJ64(C)A	64.0	71.10	78.60	1.0	1.0	103.0	29.13
SMDJ70(C)A	70.0	77.80	86.00	1.0	1.0	113.0	26.55
SMDJ75(C)A	75.0	83.30	92.10	1.0	1.0	121.0	24.79

Electrical Characteristics (T_A=25°C unless otherwise noted)

Part Number Add C For Bi-Directional (Note 4)	Reverse Standoff Voltage V _{RWM} (V)	Breakdown Voltage V _{BR} @ I _T (Note 5)		Test Current I _T (mA)	Max. Reverse Leakage @ V _{RWM} (Note 6) I _R (μA)	Max. Clamping Voltage @ I _{pp} V _c (V)	Max. Peak Pulse Current I _{pp} (A)
		Min (V)	Max (V)				
SMDJ78(C)A	78.0	86.70	95.80	1.0	1.0	126.0	23.81
SMDJ85(C)A	85.0	94.40	104.00	1.0	1.0	137.0	21.90
SMDJ90(C)A	90.0	100.0	111.00	1.0	1.0	146.0	20.55
SMDJ100(C)A	100.0	111.0	123.00	1.0	1.0	162.0	18.52
SMDJ110(C)A	110.0	122.0	135.00	1.0	1.0	177.0	16.95
SMDJ120(C)A	120.0	133.0	147.00	1.0	1.0	193.0	15.54
SMDJ130(C)A	130.0	144.0	159.00	1.0	1.0	209.0	14.35
SMDJ150(C)A	150.0	167.0	185.00	1.0	1.0	243.0	12.35
SMDJ160(C)A	160.0	178.0	197.00	1.0	1.0	259.0	11.58
SMDJ170(C)A	170.0	189.0	209.00	1.0	1.0	275.0	10.91
SMDJ180(C)A	180.0	200.0	220.00	1.0	1.0	291.6	10.29
SMDJ190(C)A	190.0	211.0	232.00	1.0	1.0	307.8	9.75
SMDJ200(C)A	200.0	224.0	247.00	1.0	1.0	324.0	9.26
SMDJ220(C)A	220.0	246.0	272.00	1.0	1.0	356.0	8.43
SMDJ250(C)A	250.0	279.0	309.00	1.0	1.0	405.0	7.41
SMDJ300(C)A	300.0	335.0	371.00	1.0	1.0	486.0	6.17
SMDJ350(C)A	350.0	391.0	432.00	1.0	1.0	567.0	5.29
SMDJ400(C)A	400.0	447.0	494.00	1.0	1.0	648.0	4.63
SMDJ440(C)A	440.0	492.0	543.00	1.0	1.0	713.0	4.21

- Notes:
4. Suffix C denotes Bi-directional device.
 5. V_{BR} measured with I_T current pulse = 300μs
 6. For Bi-Directional devices having V_{RWM} of 10V and under, the I_R is doubled.

Typical Characteristics

Fig. 1 - Peak Pulse Power Rating Curve

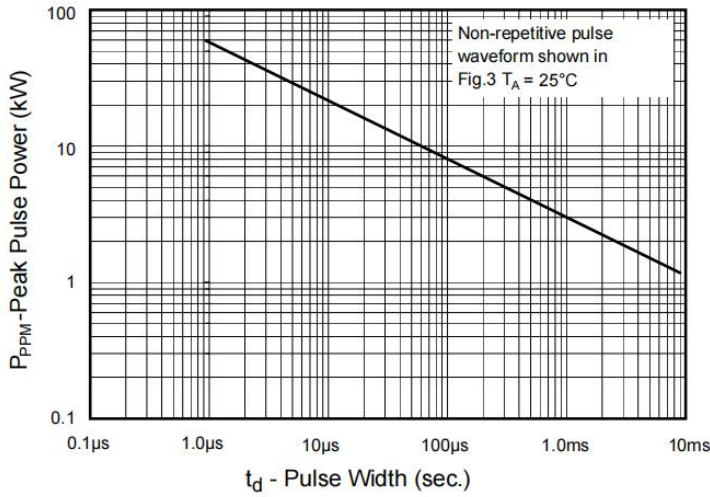


Fig.2 - Pulse Derating Curve

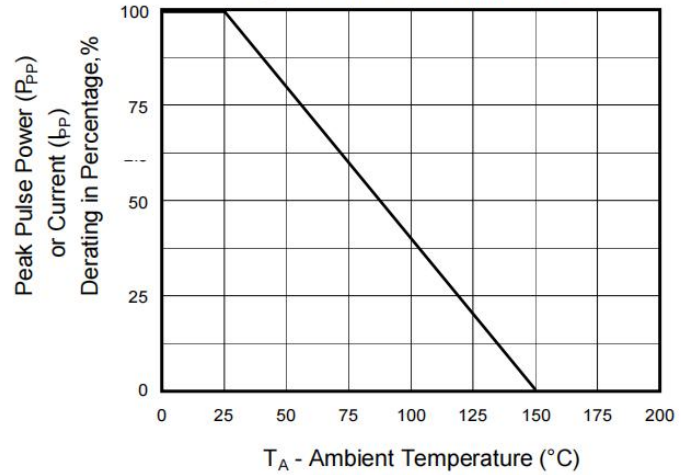


Fig.3 - Pulse Waveform

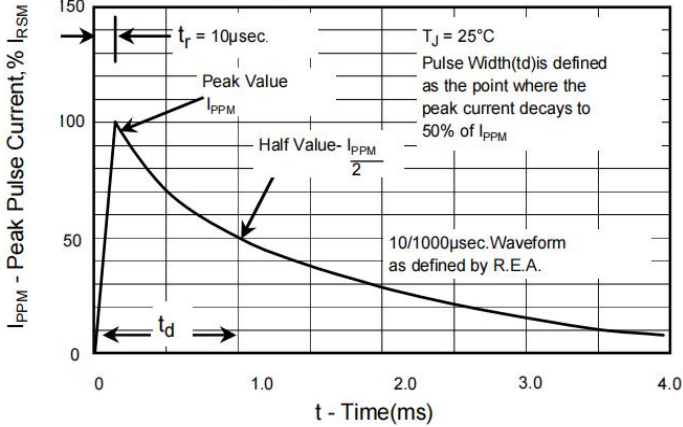


Fig. 4 - Typical Junction Capacitance

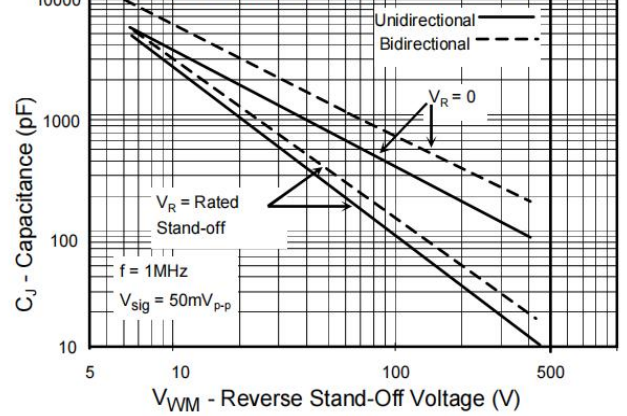


Fig. 5 - Steady State Power Derating Curve

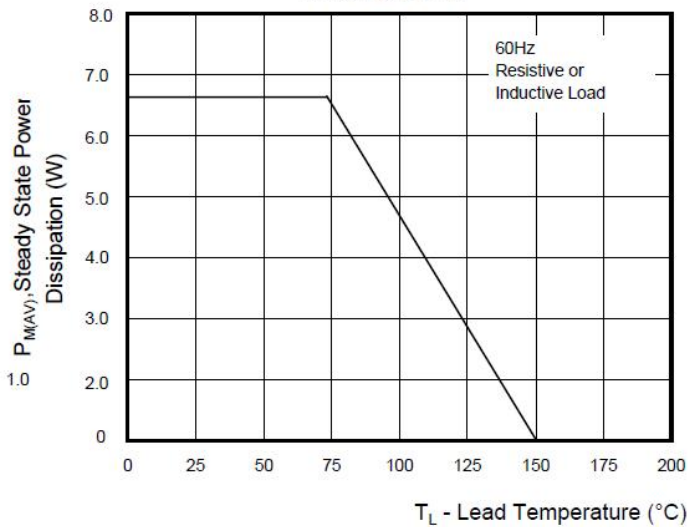
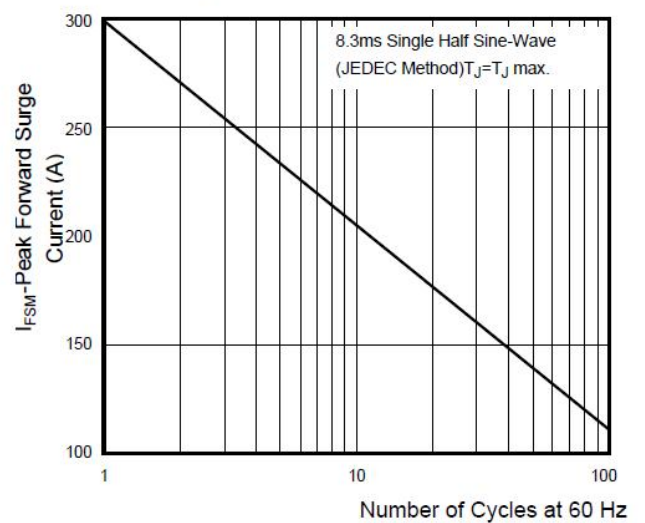
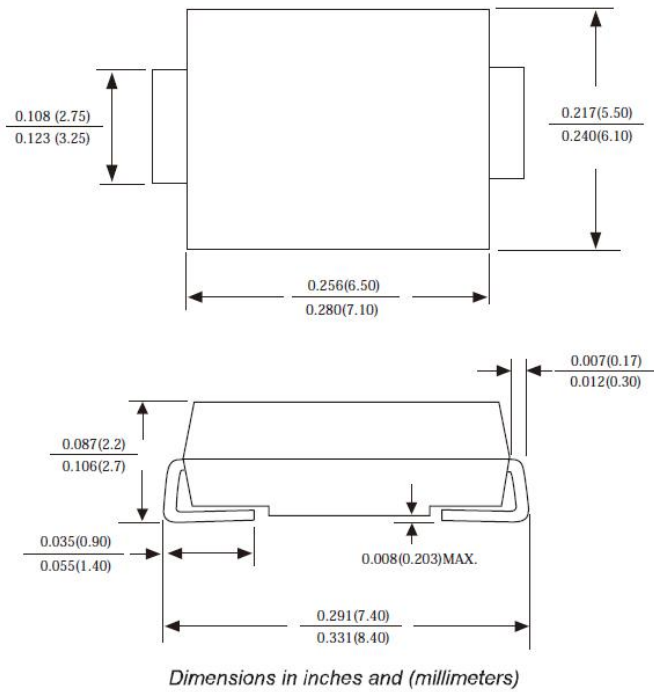


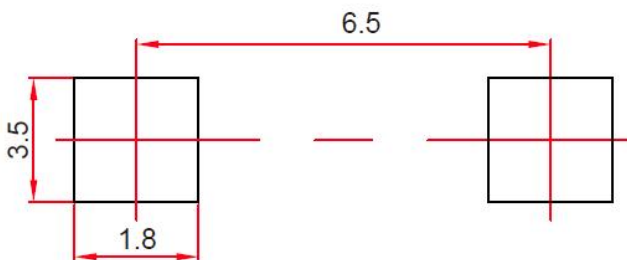
Fig.6 - Maximum Non-Repetitive Forward Surge Current Uni-Directional Only



SMCG Package Outline Dimensions



SMCG Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

NOTICE

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Reel Taping Specifications For Surface Mount Devices- SMCG

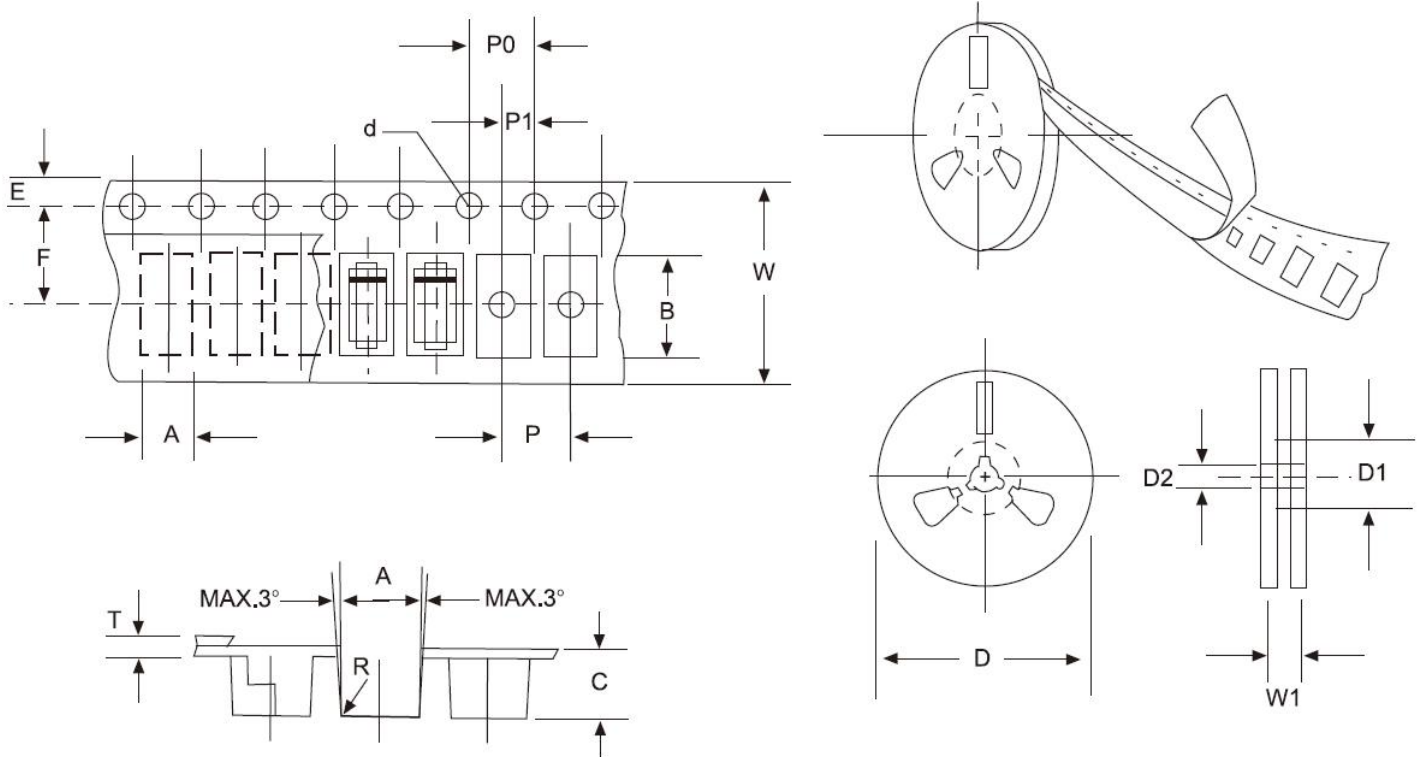


FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING

ITEM	SYMBOL	SMCG mm(inch)
Carrier width	A	6.05±0.1(0.238±0.004)
Carrier length	B	8.31±0.1(0.327±0.004)
Carrier depth	C	2.70±0.1(0.106±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	330±2.0(13±0.079)
Reel inner diameter	D1	75±1.0 (2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Sprocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	7.65±0.05(0.301±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Total tape thickness	T	0.3±0.1(0.012±0.004)
Tape width	W	16.0±0.2(0.630±0.008)
Reel width	W1	24.0±2.0(0.945±0.079)

NOTE: Devices are packed in accordance with EIA standard RS-481-A and specification given above.

Date of change	Rev #	revise content
2023/03/28	A/0	/